

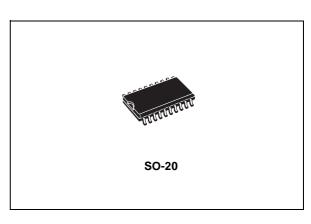
# LNB SUPPLY AND CONTROL VOLTAGE REGULATOR (PARALLEL INTERFACE)

- COMPLETE INTERFACE FOR TWO LNBs REMOTE SUPPLY AND CONTROL
- GUARANTEED 400mA OUTPUT CURRENT
- LNB SELECTION AND STAND-BY FUNCTION
- BUILT-IN TONE OSCILLATOR FACTORY TRIMMED AT 22KHz
- FAST OSCILLATOR START-UP FACILITATES DiSEqC™ ENCODING
- TWO SUPPLY INPUTS FOR LOWEST DISSIPATION
- BYPASS FUNCTION FOR SLAVE OPERATION
- LNB SHORT CIRCUIT PROTECTION AND DIAGNOSTIC
- AUXILIARY MODULATION INPUT EXTENDS FLEXIBILITY
- CABLE LENGTH COMPENSATION
- INTERNAL OVER TEMPERATURE PROTECTION
- BACKWARD CURRENT PROTECTION
- COST-EFFECTIVE VERSION OF LNBP SERIES

#### **DESCRIPTION**

Intended for analog and digital satellite receivers, the LNBK20D2 is a monolithic linear voltage regulator, assembled in SO-20, specifically designed to provide the powering voltages and the interfacing signals to the LNB downconverter situated in the antenna via the coaxial cable. It has the same functionality of the LNBP1X and LNBP20 series, at a reduced output current capability. Since most satellite receivers have two antenna ports, the output voltage of the regulator is available at one of two logic-selectable output pins (LNBA, LNBB). When the IC is powered and put in Stand-by (EN pin LOW), both regulator outputs are disabled to allow the antenna downconverters to be supplied/controlled by others satellite receivers sharing the same coaxial lines. In this occurrence the device will limit at 3 mA (max) the backward current that could flow from LNBA and LNBB output pins to GND.

For slave operation in single dish, dual receiver systems, the bypass function is implemented by an electronic switch between the Master Input pin July 2003



(MI) and the LNBA pin, thus leaving all LNB powering and control functions to the Master Receiver. This electronic switch is closed when the device is powered and EN pin is LOW.

The regulator outputs can be logic controlled to be 13 or 18 V (typ.) by mean of the VSEL pin for DataSheet4 remote controlling of LNBs. Additionally, it is possible to increment by 1V (typ.) the selected voltage value to compensate the excess voltage drop along the coaxial cable (LLC pin HIGH).

In order to reduce the power dissipation of the device when the lowest output voltage is selected, the regulator has two Supply Input pins  $V_{CC1}$  and  $V_{CC2}$ . They must be powered respectively at 16V (min) and 23V (min), and an internal switch automatically will select the suitable supply pin according to the selected output voltage. If adequate heatsink is provided and higher power losses are acceptable, both supply pins can be powered by the same 23V source without affecting any other circuit performance.

The ENT (Tone Enable) pin activates the internal oscillator so that the DC output is modulated by a ±0.3 V, 22KHz (typ.) square wave. This internal oscillator is factory trimmed within a tolerance of ±2KHz, thus no further adjustments neither external components are required.

A burst coding of the 22KHz tone can be accomplished thanks to the fast response of the ENT input and the prompt oscillator start-up. This helps designers who want to implement the DiSEq $C^{TM}$  protocols (\*).

In order to improve design flexibility and to allow implementation of newcoming LNB remote control standards, an analogic modulation input pin is Dalaoni

available (EXTM). An appropriate DC blocking capacitor must be used to couple the modulating signal source to the EXTM pin. When external modulation is not used, the relevant pin can be left open.

Two pins are dedicated to the overcurrent protection/monitoring: CEXT and OLF. The overcurrent protection circuit works dynamically: as soon as an overload is detected in either LNB output, the output is shut-down for a time Toff determined by the capacitor connected between CEXT and GND. Simultaneously the OLF pin, that is an open collector diagnostic output flag, from HIGH IMPEDANCE state goes LOW.

After the time has elapsed, the output is resumed for a time  $t_{on}$ =1/15 $t_{off}$  (typ.) and OLF goes in HIGH

IMPEDANCE. If the overload is still present, the protection circuit will cycle again through  $t_{off}$  and ton until the overload is removed. Typical  $t_{on}+t_{off}$  value is 1200ms when a 4.7 $\mu$ F external capacitor is used.

This dynamic operation can greatly reduce the power dissipation in short circuit condition, still ensuring excellent power-on start up even with highly capacitive loads on LNB outputs.

The device is packaged in Multiwatt15 for thru-holes mounting and in PowerSO-20 for surface mounting. When a limited functionality in a smaller package matches design needs, a range of cost-effective PowerSO-10 solutions is also offered. All versions have built-in thermal protection against overheating damage.

(\*): External components are needed to comply to level 2.x and above (bidirectiona) DiSEqC™ bus hardware requirements. DiSEqC™ is a trademark or EUTELSAT.

#### PIN CONFIGURATION (top view)

LLC ∏20 EXTM 1 [ OLF CEXT 2 [ ∏ 18 ENT МІ **LNBB** ∏ 17 N.C. 4 16 GND **GND** 5 [ **GND** ∏ 15 GND 6 F N.C. ከ₁₄ OSEL 7 ∏13 N.C.  $V_{CC1}$ 8 [  $\rm V_{\rm CC2}$ П 12 EN 9 [ П 11 VSEL LNBA 10 CS13800

DataShe

2/14

#### **TABLE A: PIN CONFIGURATIONS**

PIN N°	SYMBOL	NAME	FUNCTION
1	LLC	Line Length Compens. (1V typ)	Logic control input: see truth table
2	OLF	Over Load Flag	Logic output (open collector). Normally in HIGH IMPEDANCE, goes LOW when current or thermal overload occurs
3	MI	Master Input	In stand-by mode, the voltage on MI is routed to LNBA pin. Can be left open if bypass function is not needed
4	LNBB	Output Port	See truth tables for voltage and port selection
5, 6, 15, 16	GND	Ground	Circuit Ground. It is internally connected to the die frame
7, 13	N.C.	Not Connected	
8	V <sub>CC1</sub>	Supply Input 1	15V to 27V supply. It is automatically selected when $V_{OUT} = 13$ or 14V
9	V <sub>CC2</sub>	Supply Input 2	22V to 27V supply. It is automatically selected when $V_{OUT} = 18$ or 19V
10	LNBA	Output Port	See truth table voltage and port selection. In stand-by mode this port is powered by the MI pin via the internal Bypass Switch
11	V <sub>SEL</sub>	Output Voltage Selection: 13 or 18V (typ)	Logic control input: see truth table
12	EN	Port Enable	Logic control input: see truth table
14	OSEL	Port Selection	Logic control input: see truth table
18	ENT	22KHz Tone Enable	Logic control input: see truth table
19	CEXT	External Capacitor DataSho	Timing Capacitor used by the Dynamic Overload protection. Typical application is 4.7μF for a 1200ms cycle
20	EXTM	External Modulator	External Modulation Input. Needs DC decoupling to the AC source. if not used, can be left open.

NOTE: the limited pin availability of the PowerSO-10 package leads to drop some functions.

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter <sup>2</sup>	Value	Unit
VI	DC Input Voltage (V <sub>CC1</sub> , V <sub>CC2</sub> , MI)	28	V
Io	Output Current (LNBA, LNBB)	Internally Limited	mA
V <sub>I</sub>	Logic Input Voltage (ENT, EN OSEL, VSEL, LLC)	-0.5 to 7	V
I <sub>SW</sub>	Bypass Switch Current	900	mA
P <sub>D</sub>	Power Dissipation at T <sub>case</sub> < 85°C	3	W
T <sub>stg</sub>	Storage Temperature Range	-40 to +150	°C
T <sub>op</sub>	Operating Junction Temperature Range	-40 to +125	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

#### THERMAL DATA

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal Resistance Junction-case	15	°C/W

\_\_\_\_

47/

DataShe

#### **LOGIC CONTROLS TRUTH TABLE**

CONTROL I/O	PIN NAME	L	Н	
OUT	OLF	$I_{OUT} > I_{OMAX}$ or $T_j > 150$ °C	I <sub>OUT</sub> < I <sub>OMAX</sub>	
IN	ENT	22KHz tone OFF	22KHz tone ON	
IN	EN	See Table Below	See Table Below	
IN	OSEL	See Table Below	See Table Below	
IN	VSEL	See Table Below	See Table Below	
IN	LLC	See Table Below	See Table Below	

EN	OSEL	VSEL	LLCO	V <sub>LNBA</sub>	V <sub>LNBB</sub>
L	Х	X	Х	V <sub>MI</sub> - 0.4V (typ.)	Disabled
Н	L	L	L	13V (typ.)	Disabled
Н	L	Н	L	18V (typ.)	Disabled
Н	L	L	Н	14V (typ.)	Disabled
Н	L	Н	Н	19V (typ.)	Disabled
Н	Н	L	L	Disabled	13V (typ.)
Н	Н	Н	L	Disabled	18V (typ.)
Н	Н	L	Н	Disabled	14V (typ.)
Н	Н	Н	Н	Disabled	19V (typ.)

NOTE: All logic input pins have internal pull-down resistor (typ. =  $250K\Omega$ )

#### **BLOCK DIAGRAM**

DataSheet4U.com EN O PREREG. CURR.AMP. - мі OSCILLATOR ENT REFERENCE \_\_\_\_\_ 22KHz OUTPUT VOLT SELECTION VSEL ( ERR.AMP. ○ LNBA LINE LENGHT rrc 🔾 COMPENSATION ─ LNBB CURRENT LIMIT CEXT ( OUTPUT PORT SELECTION OSEL ( ─ EXTM THERMAL PROT. OLF ( SC12410

DataShe

4/14

**ELECTRICAL CHARACTERISTICS FOR LNBK SERIES** (T<sub>J</sub> = 0 to 85°C, C<sub>I</sub> =  $0.22\mu$ F, C<sub>O</sub> = $0.1\mu$ F, EN=H, ENT=L, LLC=L, V<sub>IN1</sub>=16V, V<sub>IN2</sub>=23V I<sub>OUT</sub>=50mA, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>IN1</sub>	V <sub>CC1</sub> Supply Voltage	I <sub>O</sub> = 400 mA ENT=H, VSEL=L, LLC=L	15		27	V
		I <sub>O</sub> = 400 mA ENT=H, VSEL=L, LLC=H	16		27	V
V <sub>IN2</sub>	V <sub>CC2</sub> Supply Voltage	I <sub>O</sub> = 400 mA ENT=H, VSEL=L, LLC=L	22		27	V
		I <sub>O</sub> = 400 mA VSEL=L, LLC=H	23		27	V
V <sub>O1</sub>	Output Voltage	I <sub>O</sub> = 400 mA VSEL=L, LLC=L	17.3	18	18.7	V
		I <sub>O</sub> = 400 mA ENT=H, VSEL=L, LLC=H		19		V
V <sub>O2</sub>	Output Voltage	I <sub>O</sub> = 400 mA VSEL=L, LLC=L	12.5	13	13.5	V
		I <sub>O</sub> = 400 mA ENT=H, VSEL=L, LLC=H		14		V
ΔV <sub>O</sub>	Line Regulation	V <sub>IN1</sub> =15 to 18V V <sub>OUT</sub> =13V		5	50	mV
		V <sub>IN2</sub> =22 to 25V V <sub>OUT</sub> =18V		5	50	mV
ΔV <sub>O</sub>	Load Regulation	V <sub>IN1</sub> =V <sub>IN2</sub> =22V V <sub>OUT</sub> =13 or 18V I <sub>O</sub> = 0 to 3A		65	150	mV
SVR	Supply Voltage Rejection	$V_{IN1} = V_{IN2} = 23 \pm 0.5 V_{ac} f_{ac} = 120 \text{ Hz},$		45		dB
I <sub>MAX</sub>	Output Current Limiting		500	650	800	mA
t <sub>OFF</sub>	Dynamic Overload protection OFF Time	Output Shorted C <sub>EXT</sub> =4.7μF		1100		ms
t <sub>ON</sub>	Dynamic Overload protection ON Time	Output Shorted C <sub>EXT</sub> =4.7μF		t <sub>OFF</sub> /15		ms
f <sub>TONE</sub>	Tone Frequency	ENT=H	20	22	24	KHz
A <sub>TONE</sub>	Tone Amplitude	ENT=H	0.55	0.72	0.9	Vpp
D <sub>TONE</sub>	Tone Duty Cycle	ENT=H DataSheet4U.com	40	50	60	%
t <sub>r</sub> , t <sub>f</sub>	Tone Rise and Fall Time	ENT=H	5	10	15	μs
G <sub>EXTM</sub>	External Modulation Gain	$\Delta V_{OUT}/\Delta V_{EXTM}$ , f = 10Hz to 40KHz		5		
V <sub>EXTM</sub>	External Modulation Input Voltage	AC Coupling			400	mVpp
Z <sub>EXTM</sub>	External Modulation Impedance	f = 10Hz to 40KHz		400		Ω
V <sub>SW</sub>	Bypass Switch Voltage Drop (MI to LNBA)	EN=L, I <sub>SW</sub> =300mA, V <sub>CC2</sub> -V <sub>MI</sub> =4V		0.35	0.6	V
V <sub>OL</sub>	Overload Flag Pin Logic LOW	I <sub>OL</sub> =8mA		0.28	0.5	V
I <sub>OZ</sub>	Overload Flag Pin OFF State Leakage Current	V <sub>OH</sub> = 6V			10	μΑ
V <sub>IL</sub>	Control Input Pin Logic LOW				0.8	V
V <sub>IH</sub>	Control Input Pin Logic HIGH		2.5			V
I <sub>IH</sub>	Control Pins Input Current	V <sub>IH</sub> = 5V		20		μΑ
I <sub>CC</sub>	Supply Current	Output Disabled (EN=L)		0.3	1	mA
		ENT=H, I <sub>OUT</sub> =500mA		3.1	6	mA
I <sub>OBK</sub>	Output Backward Current	EN=L $V_{LNBA} = V_{LNBB} = 18V$ $V_{IN1} = V_{IN2} = 22V$ or floating		0.2	3	mA
T <sub>SHDN</sub>	Temperature Shutdown Threshold			150		°C

et4U.com

DataShe



#### **TYPICAL CHARACTERISTICS** (unless otherwise specified T<sub>i</sub> = 25°C)

Figure 1 : Output Voltage vs Output Current

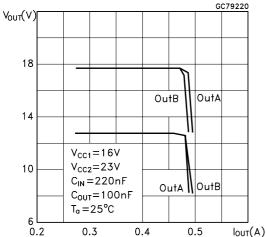


Figure 2: Tone Duty Cycle vs Temperature

Figure 4: Tone Frequency vs Temperature

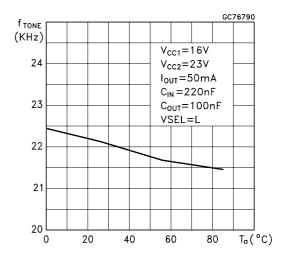


Figure 5: Tone Rise Time vs Temperature

 $V_{CC1} = \overline{16V}$ 

 $V_{CC2}=23V$ 

I<sub>OUT</sub>=50mA

 $C_{IN} = 220 nF$ 

C<sub>OUT</sub>=100nF

VSEL=L

60

 $V_{CC1} = 16V$ 

80

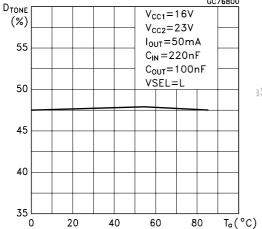
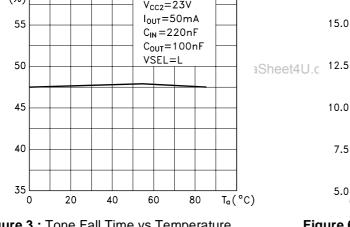


Figure 3: Tone Fall Time vs Temperature



40 Figure 6: Tone Amplitude vs Temperature

20

20



GC76900

 $V_{CC1} = \overline{16V}$ 

 $V_{CC2}=23V$ 

I<sub>OUT</sub>=50mA

 $C_{IN} = 220 nF$ 

VSEL=L

C<sub>OUT</sub>=100nF



ATONE

(mV)

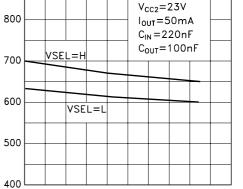
 $t_r(\mu s)$ 

15.0

10.0

7.5

5.0



40

60

80

6/14

 $t_{\rm f} (\mu {
m s})$ 

15.0

12.5

10.0

7.5

5.0

Ta(°C)

 $T_{\alpha}(^{\circ}C)$ 

GC76910

DataShe

DataSheet4U.com

Figure 7: S.V.R. vs Frequency

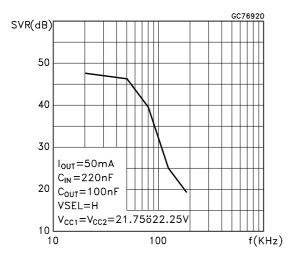


Figure 8: External Modulation vs Temperature

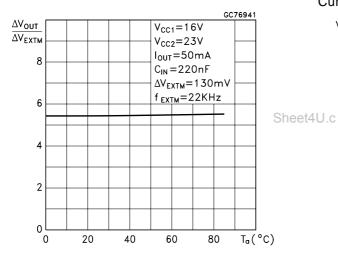
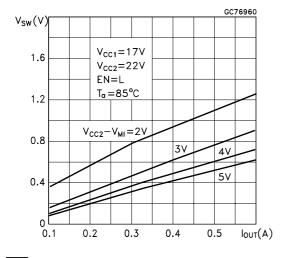


Figure 9: Bypass Switch Drop vs Output Current



**Figure 10 :** LNBA External Modulation gain vs Frequency

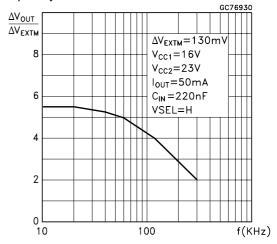


Figure 11: Bypass switch Drop vs Output Current

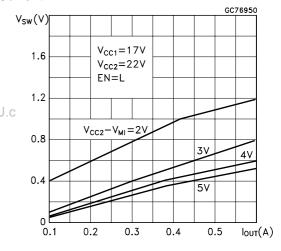
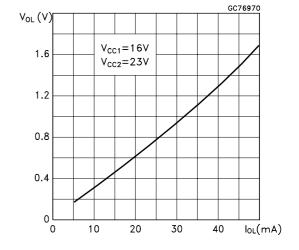


Figure 12 : overload Flag pin Logic LOW vs Flag Current



DataShe

**57** 

7/14

Figure 13: Supply Voltage vs Temperature

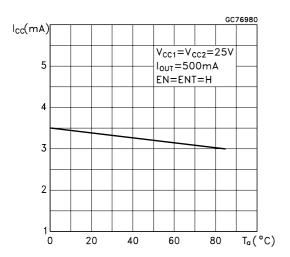


Figure 14: Supply Current vs Temperature

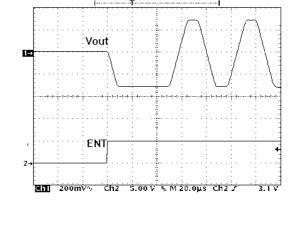
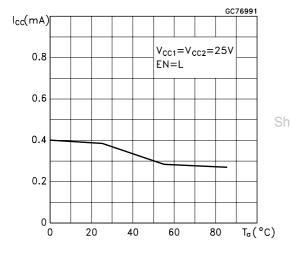


Figure 17: Tone Disable

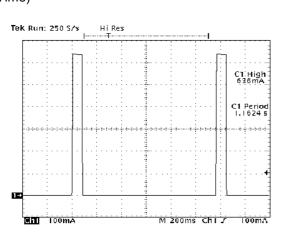
Tek **Stop:** 2.50MS/s

Figure 16: Tone Enable

Tek Run: 2.50M5/s



**Figure 15 :** Dynamic Overload protection ( $I_{SC}$  vs Time)



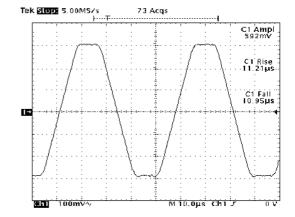
Sheet4U.(

2

ENT

200mv/> Ch2 5.00 V M 20.0µs Ch2 \ 3.1 V

Figure 18: 22KHz Tone



DataShe

Vout

8/14

Figure 19: Enable Time

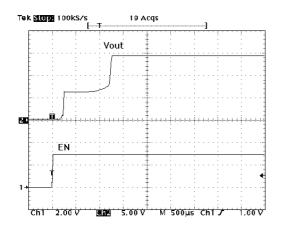


Figure 21: 18V to 13V Change

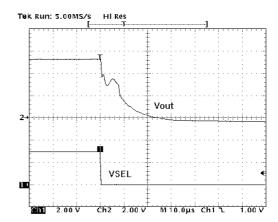


Figure 20: Disable Time

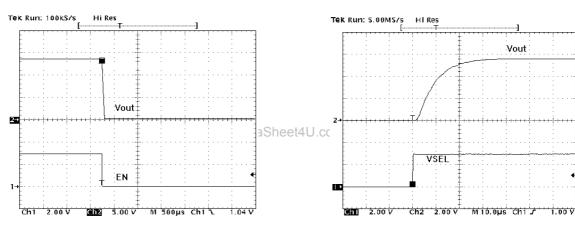


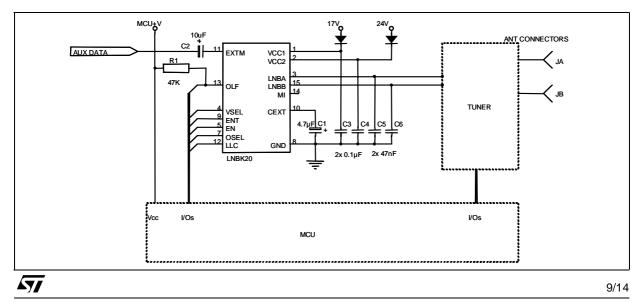
Figure 22: 18V to 13V Change

et4U.com

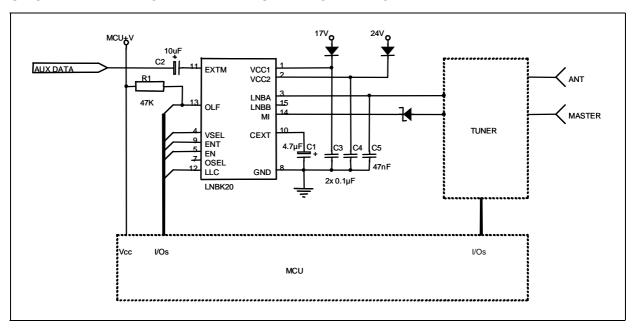
DataShe

#### **TYPICAL APPLICATION SCHEMATICS**

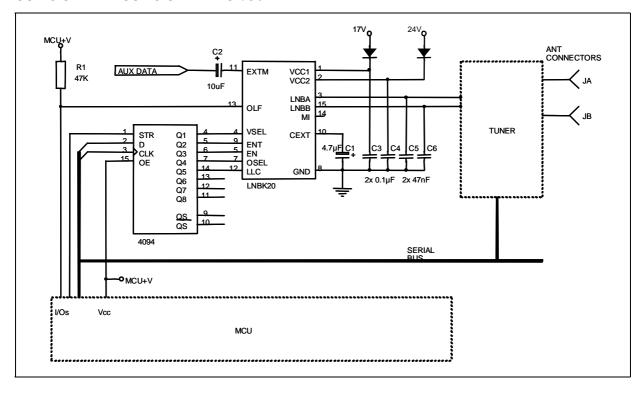
TWO ANTENNA PORTS RECEIVER



#### SINGLE ANTENNA RECEIVER WITH MASTER RECEIVER PORT



#### USING SERIAL BUS TO SAVE MPU I/Os



et4U.com

DataShe

10/14

#### THERMAL DESIGN NOTE

During normal operation, this device dissipates some power. At maximum rated output current (400mA), the voltage drop on the linear regulator lead to a total dissipated power that is of about 2W. The heat generated requires a suitable heatsink to keep the junction temperature below the over temperature protection threshold. Assuming a 40°C temperature inside the Set-Top-Box case, the total Rthj-amb has to be less than 43°C/W.

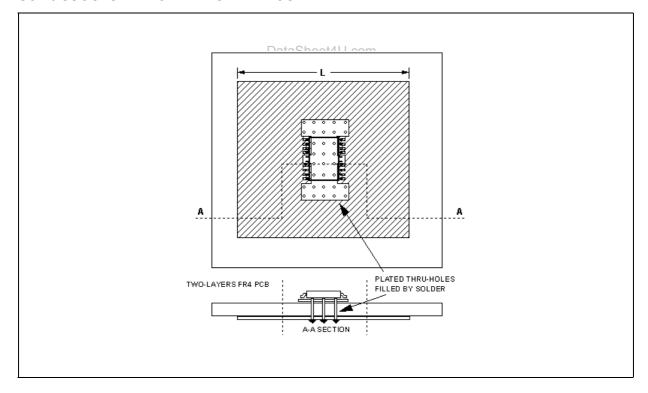
While this can be easily achieved using a through-hole power package that can be attached to a small heatsink or to the metallic frame of the receiver, a surface mount power package must rely on PCB solutions whose thermal efficiency is often limited. The simplest solution is to use a large, continuous copper area of the GND layer to dissipate the heat coming from the IC body.

The SO-20 package of this IC has 4 GND pins that are not just intended for electrical GND connection, but also to provide a low thermal resistance path between the silicon chip and the PCB heatsink. Given an Rthj-c equal to 15°C/W, a maximum of 28°C/W are left to the PCB heatsink. This figure is achieved if a minimum of  $25 \text{cm}^2$  copper area is placed just below the IC body. This area can be the inner GND layer of a multi-layer PCB, or, in a dual layer PCB, an unbroken GND area even on the opposite side where the IC is placed. In both cases, the thermal path between the IC GND pins and the dissipating copper area must exhibit a low thermal resistance.

In figure 4, it is shown a suggested layout for the SO-20 package with a dual layer PCB, where the IC Ground pins and the square dissipating area are thermally connected through 32 vias holes, filled by solder. This arrangement, when L=50mm, achieves an Rthc-a of about 28°C/W.

Different layouts are possible, too. Basic principles, however, suggest to keep the IC and its ground pins approximately in the middle of the dissipating area; to provide as many vias as possible; to design a dissipating area having a shape as square as possible and not interrupted by other copper traces.

#### SO-20 SUGGESTED PCB HEATSINK LAYOUT



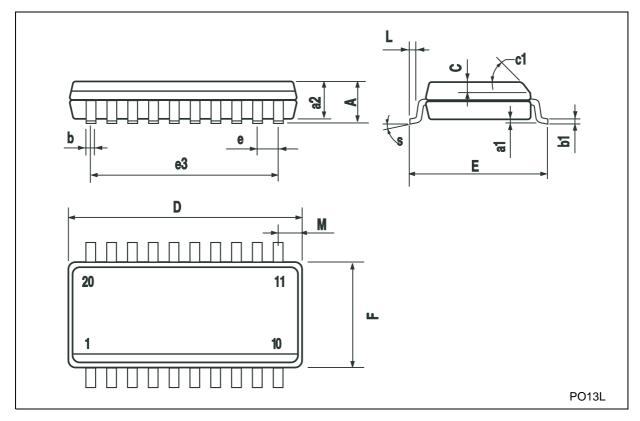
DataS

# **SO-20 MECHANICAL DATA**

DIM.	mm.			inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			2.65			0.104	
a1	0.1		0.2	0.004		0.008	
a2			2.45			0.096	
b	0.35		0.49	0.014		0.019	
b1	0.23		0.32	0.009		0.012	
С		0.5			0.020		
c1			45°	(typ.)			
D	12.60		13.00	0.496		0.512	
E	10.00		10.65	0.393		0.419	
е		1.27			0.050		
e3		11.43			0.450		
F	7.40		7.60	0.291		0.300	
L	0.50		1.27	0.020		0.050	
М			0.75			0.029	
S			8° (r	nax.)			

et4U.com

DataShe



12/14

# Tape & Reel SO-20 MECHANICAL DATA

DIM.	mm.			inch			
DIIVI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
N	60			2.362			
Т			30.4			1.197	
Ao	10.8		11	0.425		0.433	
Во	13.2		13.4	0.520		0.528	
Ko	3.1		3.3	0.122		0.130	
Ро	3.9		4.1	0.153		0.161	
Р	11.9		12.1	0.468		0.476	

A Po

et4U.com

DataShe



Note: Drawing not in scale

Αo

Κo

et4U.com

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2003 STMicroelectronics - Printed in Italy - All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco Singapore - Spain - Sweden - Switzerland - United Kingdom - United States. © http://www.st.com

**477** 

14/14